



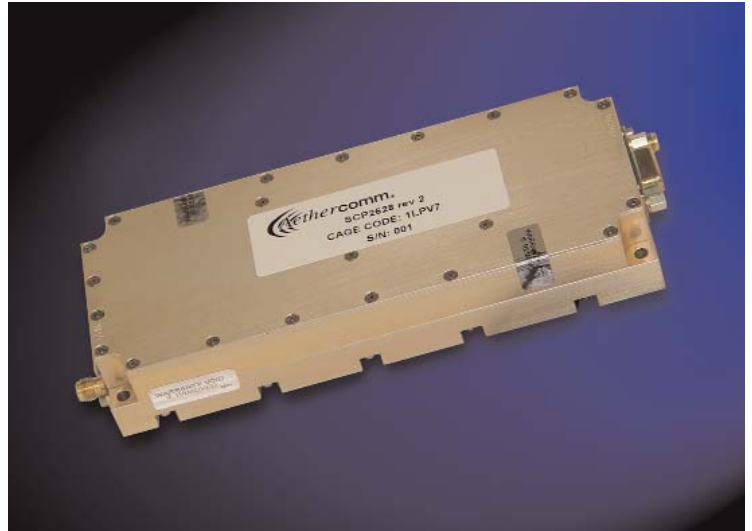
GaN Broadband Power Amplifier

Solid State RF Amplifier

Aethercomm Model Number SSPA 1.65-2.50-30 is a high power, broadband, Gallium Nitride (GaN) RF amplifier that operates from 1650 MHz to 2500 MHz. This PA is ideal for broadband military platforms as well as commercial applications because it is robust and offers high power over a large bandwidth with decent power added efficiency. This amplifier was designed for broad band jamming and communication systems platforms. This amplifier operates with a base plate temperature of 85C with no degradation in the MTBF for the GaN devices inside. It is packaged in a modular housing that is approximately 2.5" (width) by 6.4" (long) by 1.00" (height). This amplifier has a typical P3dB of 30-45 watts at room temperature. Noise figure at room temperature is 9.0 dB typical. This amplifier offers a typical gain of 51 dB with a typical gain flatness of ± 1.0 dB. The power and gain flatness across the band is extremely flat for the bandwidth. Input VSWR is 2.0:1 maximum. Class AB quiescent current is ~1.43 amps typical employing a +48 Vdc supply. This PA operates from a +48 Vdc input voltage. Typical harmonic values can be found on the next page of this data sheet. Typical OIP3 levels are 51 dBm with two tones at 37dBm each tone with a 1MHz spacing.

This SSPA includes an external DC blanking command that enables and disables the module in 20.0 uSec maximum. A logic low or open circuit enables the amplifier. A logic high will disable the amplifier. Standard features include over/under voltage protection and reverse polarity protection. The output is fully protected from an open or short circuit presented to this port with no damage. Input/output RF connectors are SMA female. DC and command voltages are accessible via a DSUB connector. Contact the factory with any questions you may have. This amplifier operates from -40C to +85C

- **Gallium Nitride Broadband Power Amplifier**
- **Operation from 1.65 GHz to 2.5 GHz min**
- **Small Signal Gain 51 dB typical**
- **30-40 Watts P3dB typical**



base plate temperature. Summary test data is found on sheet two of this data sheet at room temperature.

This is an example of an Aethercomm standard product. Aethercomm designs and manufactures high performance, high power CW or pulsed SSPA's for commercial, military and satellite communications customer.

Aethercomm Inc. reserves the right to make changes without further notice. Aethercomm recommends that before these items herein are specified into a system or critical application that the performance characteristics be verified by contacting the factory.

SSPA 1.65-2.50-30

SSPA 1.65-2.50-30 Typical Performance @ 25°C

Freq (MHz)	Small Signal Gain (dB)	Pout @ Pin = 0 dBm (dBm)	Current @ PSat from a +48 Vdc Supply (Amps)	2nd Harmonic @ Pout = 10 Watts (dBc)	3rd Harmonic @ Pout = 10 Watts (dBc)	Power Added Efficiency @ PSat (%)
1650	51.1	44.9	2.59	-34.3	-41.2	26.8
1820	53.5	47.1	3.46	-40.5	-31.4	32.4
1990	52.1	45.6	3.16	-42.3	-50.2	25.6
2160	50.7	44.9	2.71	-43.2	-54.2	25.6
2330	51.4	46.8	2.86	-40.1	<-60.0	36.7
2500	50.7	45.7	2.14	-21.2	<-60.0	38.7